

View Online at <https://aerobasegroup.com/nsn/5961-00-477-1020>

Inclosure Material:

Metal all semiconductor device diode

Overall Length:

1.750 inches all semiconductor device diode

Overall Diameter:

1.120 inches all semiconductor device diode

Mounting Facility Quantity:

1 2nd semiconductor device diode

Internal Configuration:

Junction contact all semiconductor device diode

Internal Junction Configuration:

Pn all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

2 semiconductor device diode

Mounting Method:

Threaded stud all semiconductor device diode and unthreaded hole all semiconductor device diode

Features Provided:

Hermetically sealed case

Thread Size:

0.312 inches all semiconductor device diode

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

200.0 reverse voltage, dc all semiconductor device diode

Current Rating Per Characteristic:

600.00 amperes peak forward surge current megahertz all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius ambient air all semiconductor device diode

Thread Series Designator:

Unc all semiconductor device diode

Terminal Type And Quantity:

1 unthreaded hole 2nd semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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